

**Features**

- Halogen Free. "Green" Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

**Maximum Ratings @ 25°C Unless Otherwise Specified**

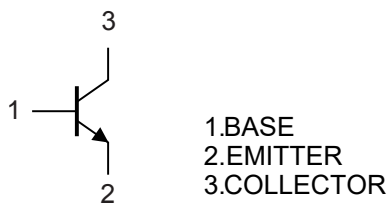
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 625°C/W Junction to Ambient

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	50	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Continuous Collector Current	$I_C$	100	mA
Power Dissipation	$P_D$	200	mW

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

**NPN Silicon Epitaxial Transistors**

**Internal Structure**



**SOT-23**

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.110	0.120	2.80	3.04	
B	0.083	0.104	2.10	2.64	
C	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
E	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
H	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

**Suggested Solder Pad Layout**

inches  
mm

**Electrical Characteristics @  $T_A=25^\circ\text{C}$  Unless Otherwise Specified**

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Cutoff Current	$I_{CBO}$			0.1	$\mu\text{A}$	$V_{CB}=60\text{V}, I_E=0$
Emitter-Base Cutoff Current	$I_{EBO}$			0.1	$\mu\text{A}$	$V_{EB}=5\text{V}, I_C=0$
DC Current Gain	$h_{FE}$	135		600		$V_{CE}=6\text{V}, I_C=1\text{mA}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		0.15	0.3	V	$I_C=100\text{mA}, I_B=10\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		0.86	1.00	V	$I_C=100\text{mA}, I_B=10\text{mA}$
Base-Emitter Voltage	$V_{BE}$	0.55	0.62	0.65	V	$V_{CE}=6\text{V}, I_C=1\text{mA}$
Transition Frequency	$f_T$		250		MHz	$V_{CE}=6\text{V}, I_C=10\text{mA}$
Collector Output Capacitance	$C_{ob}$		3		pF	$V_{CB}=6\text{V}, I_E=0, f=1\text{MHz}$

**Classification of  $h_{FE}$** 

Rank	L5	L6	L7
Range	135-270	200-400	300-600
Marking	L5	L6	L7

**Curve Characteristics**

Fig. 1 - Static Characteristics

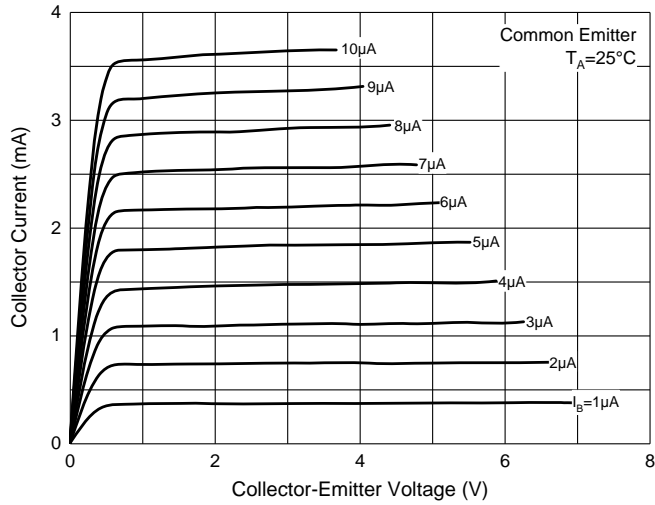


Fig. 2 - DC Current Gain Characteristics

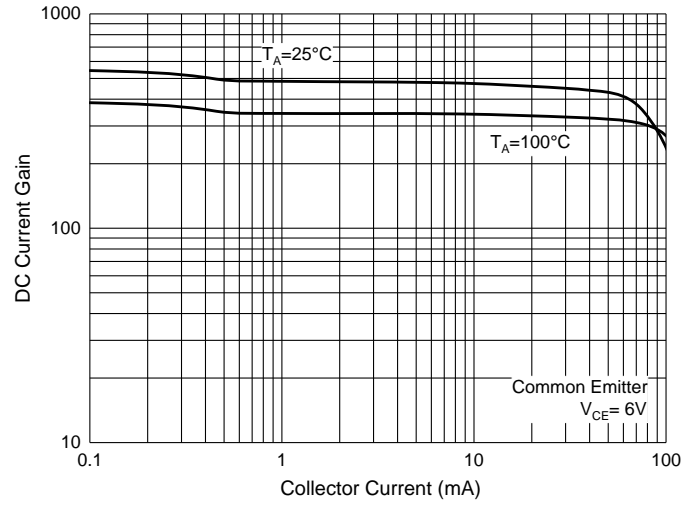


Fig. 3 - Base-Emitter Saturation Voltage Characteristics

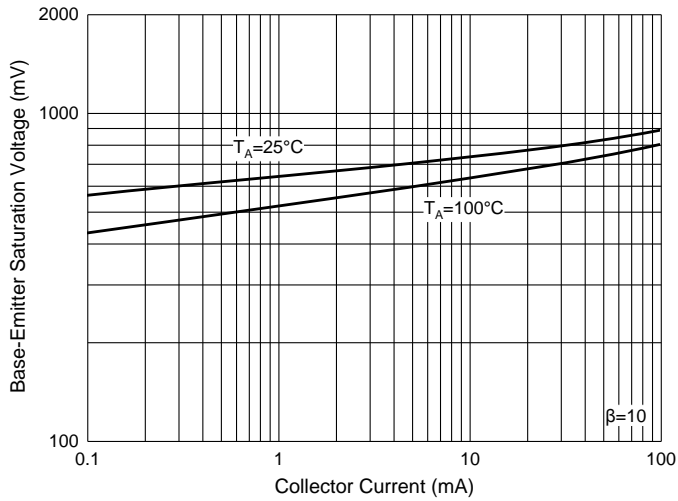


Fig. 4 - Collector-Emitter Saturation Voltage Characteristics

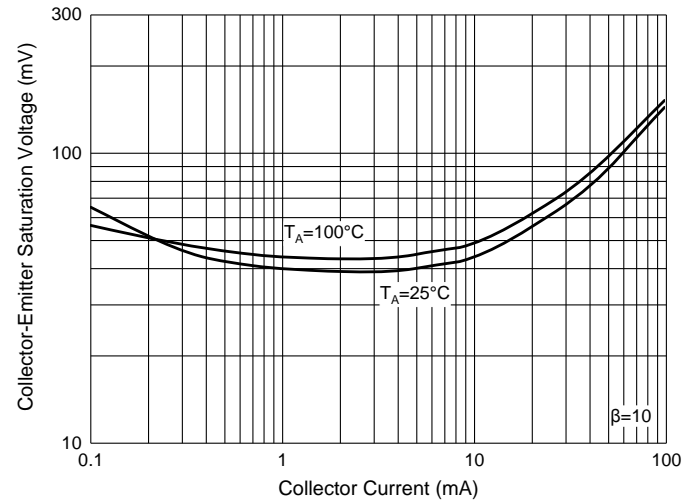


Fig. 5 - Base-Emitter Voltage Characteristics

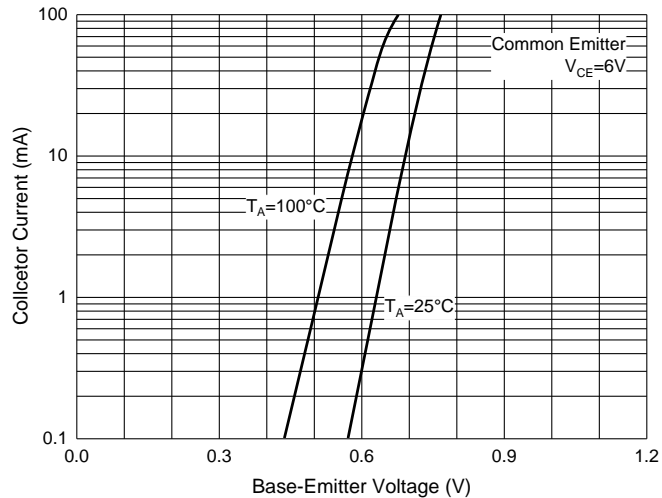


Fig. 6 - Collector Power Derating Curve

